

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L2	4	"365"/\$.ccls. and (heat\$3 with high with resistan\$4) and (heat\$3 with low with resistan\$4) and (heat\$4 with device) and (field adj2 effect)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/27 11:33
L3	15	"365"/\$.ccls. and (heat\$3 with high with resistan\$4) and (heat\$3 with low with resistan\$4) and (heat\$4 with device)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/27 12:06
L4	11	I3 not I2	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/27 11:34
L6	7	("20030076703"   "5439833"   "5640343"   "6215140"   "6339544"   "6552926"   "6597031").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/01/27 11:42
L7	5	("5684737"   "5694355"   "5838609"   "5870329"   "6075720").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/01/27 11:46
L8	6	365/158,243,163,113,105,96,103, 104,175.ccls. and (heat\$3 with high with resistan\$4) and (heat\$3 with low with resistan\$4) and (heat\$4 with device)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/27 12:14
L9	1	365/158,243,163,113,105,96,103, 104,175.ccls. and (heat\$4 with switch\$3 with (field-effect with transistor) with drain)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/27 13:02
L10	1	"365"/\$.ccls. and (heat\$4 with switch\$3 with (field-effect with transistor) with drain)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/27 12:16
L11	3	(heat\$4 with switch\$3 with (field-effect with transistor) with drain)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/27 12:16
L12	3	("4547706"   "5422546"   "5589740").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/01/27 12:21

L13	1	365/158,243,163,113,105,96,103,104,177,175.ccls. and (heat\$4 with switch\$3 with (field-effect with transistor) with drain)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/27 13:05
L14	1	365/158,163,113,105,96,103,104,171,177,175.ccls. and (heat\$4 with switch\$3 with (field-effect with transistor) with drain)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/27 13:06
L15	1	365/158,163,113,105,96,103,104,171,177,175.ccls. and ((heat\$3 or thermal) near diode and (zener adj diode\$1))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/27 13:07
L16	3	365/158,163,113,105,96,103,104,171,177,175.ccls. and high-resistance same low-resistance same heat	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/27 13:07
L17	1	365/158,163,113,105,96,103,104,171,177,175.ccls. and (nonvolatile or non\$volatile or non-volatile or flash) and (heat\$3 with high with resistanc\$4) and (heat\$3 with low with resistanc\$4) and (heat\$4 with device) and (field adj2 effect)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/27 13:08
S1	101	high-resistance same low-resistance same heat	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/27 13:07
S2	4	"365"/\$.ccls. and high-resistance same low-resistance same heat	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/04 11:37
S3	4	("4177475"   "4203123"   "4499557"   "4531144").PN.	USPAT	OR	OFF	2004/09/04 11:33
S4	1	high-resistance same low-resistance same heat same switch\$3 same transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/04 11:39
S5	10	high-resistance same low-resistance same heat same switch\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/04 11:56

S6	5	("1758703"   "2360299"   "3475588"   "3624354"   "3982092").PN.	USPAT	OR	OFF	2004/09/04 11:42
S7	333	(heat with rate) same transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/17 11:36
S8	3	"365"/\$.ccls. and (heat with rate) same transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/04 11:59
S9	2	("5119329"   "5506748").PN.	USPAT	OR	OFF	2004/09/04 11:58
S10	73	(heat with rate) same switch\$3 same transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/04 11:59
S11	637	ovonic	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/07 08:36
S12	1	ovonic same (heat\$3 with rate\$1)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/07 07:37
S13	40	ovonic same heat\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/07 08:09
S14	15	ovonic same transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/07 08:10
S15	77	"365"/\$.ccls. and ovonic	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/07 08:36
S16	60	"365"/\$.ccls. and ovonic and transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/07 10:08

S17	8	"365"/\$.ccls. and ovonic and transistor near4 heat\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/07 10:17
S18	32	"365"/\$.ccls. and ovonic and transistor and heat\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/07 10:43
S19	60	"365"/\$.ccls. and ovonic and transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/07 12:13
S20	19	"365"/\$.ccls. and ovonic and (transistor with array\$1)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/07 12:23
S21	2	("5363329"   "5920788").PN.	USPAT	OR	OFF	2004/09/07 12:15
S22	2	"365"/\$.ccls. and (ovonic with heat\$3) and (transistor with array\$1)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/07 12:24
S23	19	"365"/\$.ccls. and (ovonic or phase-changeable) and (transistor with array\$1)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/07 12:25
S24	8	"365"/\$.ccls. and (ovonic or phase-changeable) and (transistor with array\$1) and heat\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/07 12:26
S25	12	(ovonic or phase-changeable) and (transistor with array\$1) and heat\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/07 12:47
S26	6	("5439833"   "5640343"   "6215140"   "6339544"   "6552926"   "6597031"   "2003/0076703").PN.	USPAT	OR	OFF	2004/09/07 12:27
S27	2	("5363329"   "5920788").PN.	USPAT	OR	OFF	2004/09/07 12:28
S28	3	("3206730"   "3488636"   "3201764").PN.	USPAT	OR	OFF	2004/09/07 12:29

S29	2	("5296716"   "6087674"   "2003/0186481"   "2003/0206512").PN.	USPAT	OR	OFF	2004/09/07 12:29
S30	32	(ovonic or phase-changeable) and (transistor with array\$1)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/07 12:45
S31	7	(ovonic or phase-changeable) and (transistor near4 array\$1) and heat\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/07 13:32
S32	50	(ovonic or phase-changeable) and (switch\$3 with transistor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/07 13:33
S33	9	(ovonic or phase-changeable) and (switch\$3 with transistor with heat\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/07 13:34
S34	4	("6191973"   "6625054"   "6673691"   "6700813").PN.	USPAT	OR	OFF	2004/09/07 13:35
S35	49158	(heat\$3 or thermal) near5 cell\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/17 11:37
S36	301	"365"/\$158,243,163.ccls. and (heat\$3 or thermal) near5 cell\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/08 15:42
S37	24	"365"/\$158,243,163.ccls. and (heat\$3 or thermal) near5 cell\$3 with transistor\$1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/08 15:50
S38	26	365/158,243,163.ccls. and (heat\$3 or thermal) near5 cell\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/08 15:52
S39	14	365/158,243,163.ccls. and (heat\$3 or thermal) near5 cell\$3 and transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/08 16:09



S40	15	365/158,243,163,113.ccls. and (heat\$3 or thermal) near5 cell\$3 and transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/09 13:27
S41	10	"365"/\$.ccls. and (heat\$3 or thermal) near5 drain near5 cell\$1 and transistor\$1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/08 16:24
S42	31	"365"/\$.ccls. and drain with (heat\$3 or thermal) near5 cell\$1 and transistor\$1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/08 16:40
S43	3	drain near3 (heat\$3 or thermal) near5 cell\$1 and transistor\$1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/08 16:49
S44	7	("4165642"   "4734641"   "5309090"   "5414370"   "5473259"   "5886564"   "5911897").PN.	USPAT	OR	OFF	2004/09/08 16:42
S45	45	drain near5 (heat\$3 or thermal) near5 cell\$1 and transistor\$1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/08 16:49
S46	35	365/158,243,163,113,105,96,103, 104,175.ccls. and (heat\$3 or thermal) near5 cell\$3 and transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/09 13:29
S47	30	365/158,243,163,113,105,96,103, 104,175.ccls. and (heat\$3 or thermal) near5 diode	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/26 19:46
S48	10	365/158,243,163,113,105,96,103, 104,175.ccls. and ((heat\$3 or thermal) near diode)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/15 09:35
S49	1	365/158,243,163,113,105,96,103, 104,175.ccls. and ((heat\$3 or thermal) near diode and (zener adj diode\$1))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/09 13:50

S50	1	"365"/\$.ccls. and ((heat\$3 or thermal) near diode and (zener adj diode\$1))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/09 13:51
S51	118	((heat\$3 or thermal) near diode and (zener adj diode\$1))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/27 13:06
S52	75	((heat\$3 or thermal) near diode and (zener adj diode\$1)) and transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/09 13:52
S53	1	365/158,243,163,113,105,96,103,104,175.ccls. and ((heat\$3 or thermal) near diode and (zener adj diode\$1))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/09 14:04
S54	3	365/158,243,163,113,105,96,103,104,175.ccls. and ((heat\$3 or thermal) near5 diode and (zener adj diode\$1))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/09 14:07
S55	4	"365"/\$.ccls. and ((heat\$3 or thermal) near5 diode and (zener adj diode\$1))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/09 14:11
S56	14	((heat\$3 or thermal) near5 diode and (zener adj diode\$1)) and (thermal adj resistor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/09 14:16
S57	9	((heat\$3 or thermal) near5 diode and (zener adj diode\$1)) and (thermal adj resistor) and transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/09 14:16
S58	1	heat\$3 near4 switch\$3 near4 memory near4 diode	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/15 08:59
S59	7	"365"/\$.ccls. and heat\$3 same switch\$3 same memory same diode	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/15 09:12

S60	9	heat\$3 with switch\$3 with memory with diode	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/15 09:13
S61	104	heat\$3 same switch\$3 same memory same diode	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/15 09:15
S62	2	("4649333"   "6002239").PN.	USPAT	OR	OFF	2004/09/15 09:23
S63	30	365/158,243,163,113,105,96,103,104,175.ccls. and ((heat\$3 or thermal) near5 diode)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/15 09:36
S64	1	365/158,243,163,113,105,96,103,104,175.ccls. and ((heat\$3 or thermal) near5 switch\$3 near5 memory near5 diode)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/15 09:37
S65	3	365/158,243,163,113,105,96,103,104,175.ccls. and ((heat\$3 or thermal) same switch\$3 same memory same diode)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/17 11:31
S66	4	("3612758"   "3681754"   "5592409"   "5889694").PN.	USPAT	OR	OFF	2004/09/15 09:42
S67	9	"365"/\$.ccls. and ((heat\$3 or thermal) same switch\$3 same memory same diode)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/15 09:45
S68	130	((heat\$3 or thermal) same switch\$3 same memory same diode)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/15 09:45
S69	3	365/158,243,163,113,105,96,103,104,175.ccls. and high-resistance same low-resistance same heat	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/17 11:20
S70	305	"365"/\$.ccls. and (heat\$3 or thermal) near5 cell\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/17 11:55



S71	100	365/158,175,113,163,171,189.03, 177,105,148,149,185.11.ccls. and (heat\$3 or thermal) near5 cell\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/17 11:57
S72	26	365/158,175,113,163,171,189.03, 177,105,148,149,185.11.ccls. and (heat\$3 or thermal) near5 cell\$3 and transistor\$1 and diode	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/17 11:57
S73	26	365/158,175,113,163,171,189.03, 177,105,148,149,185.11.ccls. and (heat\$3 or thermal) near5 cell\$3 and \$8transistor and diode	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/17 11:58
S74	1	365/158,243,163,113,105,96,103, 104,175.ccls. and (nonvolatile or non\$volatile or non-volatile or flash) and (heat\$3 with high with resistan\$4) and (heat\$3 with low with resistan\$4) and (field adj2 effect)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/26 20:08
S75	74	(nonvolatile or non\$volatile or non-volatile or flash) and (heat\$3 with high with resistan\$4) and (heat\$3 with low with resistan\$4) and (field adj2 effect)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/26 19:50
S76	21	"365"/\$.ccls. and (nonvolatile or non\$volatile or non-volatile or flash) and (heat\$3 with high with resistan\$4) and (heat\$3 with low with resistan\$4) and (field adj2 effect)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/26 19:56
S77	40	("4402065"   "4698750"   "4701886"   "4783764"   "4785425"   "4794588"   "4796235"   "4807114"   "4887234"   "4953129"   "4974208"   "4975878"   "5065364"   "5070473"   "5088023"   "5097445"   "5109359"   "5175840"   "5185718"   "5199001"   "5200600"   "5222046"   "5255237"   "5255244"   "5283758"   "5297096"   "5305276"   "5305284"   "5321845"   "5329492"   "5369647"   "5377145"   "5390146"   "5402383"   "5418752"   "5444664"   "5566125"   "5581503"   "5602738"   "5615159").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/01/26 19:55

S78	21	"365"/\$.ccls. and (nonvolatile or non\$volatile or non-volatile or flash) and (heat\$3 with high with resistanc\$4) and (heat\$3 with low with resistanc\$4) and (field with effect with transistor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/26 19:58
S79	35	(nonvolatile or non\$volatile or non-volatile or flash) and (heat\$3 with high with resistanc\$4) and (heat\$3 with low with resistanc\$4) and (field with effect with transistor) and (drain with region) and (heat\$4 with region)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/26 19:59
S80	41	("4402065"   "4698750"   "4701886"   "4783764"   "4785425"   "4794558"   "4796235"   "4807114"   "4887234"   "4953129"   "4974208"   "4975878"   "5065364"   "5070473"   "5088023"   "5097445"   "5109359"   "5175840"   "5185718"   "5199001"   "5200600"   "5222046"   "5255237"   "5255244"   "5283758"   "5297096"   "5305276"   "5305284"   "5321845"   "5329492"   "5369647"   "5377145"   "5390146"   "5402383"   "5418237"   "5444664"   "5566125"   "5581503"   "5602738"   "5615159"   "6064593").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/01/26 20:06
S81	13	("4690730"   "4784973"   "4931411"   "5330921"   "5358893"   "5518958"   "5536947"   "5543362"   "5545574"   "5585300"   "5739064"   "5766991"   "5874351").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/01/26 20:07
S82	1	365/158,243,163,113,105,96,103,104,175.ccls. and (nonvolatile or non\$volatile or non-volatile or flash) and (heat\$3 with high with resistanc\$4) and (heat\$3 with low with resistanc\$4) and (heat\$4 with device) and (field adj2 effect)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/26 20:09
S83	1	"365"/\$.ccls. and (nonvolatile or non\$volatile or non-volatile or flash) and (heat\$3 with high with resistanc\$4) and (heat\$3 with low with resistanc\$4) and (heat\$4 with device) and (field adj2 effect)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/26 20:09

S84	26	(nonvolatile or non\$volatile or non-volatile or flash) and (heat\$3 with high with resistanc\$4) and (heat\$3 with low with resistanc\$4) and (heat\$4 with device) and (field adj2 effect)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/27 13:08
S85	5	(nonvolatile or non\$volatile or non-volatile or flash) and (heat\$4 with device) and low\$resistan\$3 and high\$resistan\$3 and (field adj2 effect)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/26 20:19
S86	18	("20020102834"   "20020119651"   "6048789"   "6136680"   "6143658"   "6153523"   "6159857"   "6165894"   "6171957"   "6174810"   "6181012"   "6242349"   "6291007"   "6348402"   "6355571"   "6482755"   "6521532"   "6534397").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/01/26 20:14
S87	2	"6,433567".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/26 20:16
S88	7	("4165642"   "4734641"   "5309090"   "5414370"   "5473259"   "5886564"   "5911897").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/01/26 20:16
S89	1	365/158,243,163,113,105,96,103,104,175.ccls. and (nonvolatile or non\$volatile or non-volatile or flash) and (heat\$4 with device) and low\$resistan\$3 and high\$resistan\$3 and (field adj2 effect)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/26 20:20
S90	10	365/158,243,163,113,105,96,103,104,175.ccls. and (nonvolatile or non\$volatile or non-volatile or flash) and (heat\$4 with device) and (field adj2 effect)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/26 20:20
S91	4	("6191973"   "6625054"   "6673691"   "6700813").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/01/26 20:22

S92	64	("3576549"   "3582908"   "3634929"   "3671948"   "3717852"   "3728695"   "3787822"   "3863231"   "3990098"   "4146902"   "4203123"   "4203158"   "4229757"   "4272880"   "4281397"   "4419741"   "4420766"   "4442507"   "4489478"   "4494135"   "4498226"   "4499557"   "4507757"   "4543594"   "4569121"   "4646266"   "4820657"   "4823181"   "4855953"   "4876220"   "4881114"   "4899205"   "4922319"   "4943538"   "5070383"   "5070384"   "5126290"   "5233206"   "5306935"   "5311039"   "5334880"   "5391518"   "5427979"   "5441907"   "5463244"   "5467305"   "5508971"   "5535156"   "5536968"   "5596532"   "5640343"   "5675547"   "5737259"   "5745407"   "5751012"   "5751629"   "5776810"   "5793697"   "5818748"   "5835396"   "5883409"   "6034882"   "6055180"   "6185122"   "B14203158").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/01/26 20:24
S93	3	("5173873"   "5432734"   "5898612").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/01/26 20:28